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Front Matter: Volume 7784

, "Front Matter: Volume 7784," Proc. SPIE 7784, Tenth International Conference on Solid State Lighting, 778401 (1 September 2010); doi: 10.1117/12.878987

SPIE.

Event: SPIE Optical Engineering + Applications, 2010, San Diego, California, United States

PROCEEDINGS OF SPIE

Tenth International Conference on Solid State Lighting

**Ian Ferguson
Matthew H. Kane
Nadarajah Narendran
Tsunemasa Taguchi**
Editors

**2–4 August 2010
San Diego, California, United States**

Sponsored and Published by
SPIE

Volume 7784

Proceedings of SPIE, 0277-786X, v. 7784

SPIE is an international society advancing an interdisciplinary approach to the science and application of light.

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Author(s), "Title of Paper," in *Tenth International Conference on Solid State Lighting*, edited by Ian Ferguson, Matthew H. Kane, Nadarajah Narendran, Tsunemasa Taguchi, Proceedings of SPIE Vol. 7784 (SPIE, Bellingham, WA, 2010) Article CID Number.

ISSN 0277-786X

ISBN 9780819482808

Published by

SPIE

P.O. Box 10, Bellingham, Washington 98227-0010 USA

Telephone +1 360 676 3290 (Pacific Time) · Fax +1 360 647 1445

SPIE.org

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